- Meets or Exceeds the Requirements of ANSI Standards EIA/TIA-422-B and EIA/TIA-423-B and ITU Recommendations V.10 and V.11
- 3-State, TTL-Compatible Outputs
- Fast Transition Times
- Operates From Single 5-V Supply
- Designed to Be Interchangeable With Motorola™ MC3486

description

The MC3486 is a monolithic quadruple differential line receiver designed to meet the specifications of ANSI Standards EIA/TIA-422-B and EIA/TIA-423-B and ITU Recommendations V.10 and V.11. The MC3486 offers four independent differential-input line receivers that have TTL-compatible outputs. The outputs utilize 3-state circuitry to provide a high-impedance state at any output when the appropriate output enable is at a low logic level.

The MC3486 is designed for optimum performance when used with the MC3487 quadruple differential line driver. It is supplied in a 16-pin package and operates from a single 5-V supply.

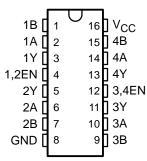
The MC3486 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE (each receiver)

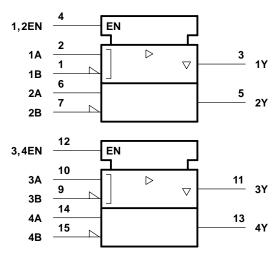
DIFFERENTIAL INPUTS A-B	ENABLE	OUTPUT Y
V _{ID} ≤ 0.2 V	Н	Н
$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$	Н	?
V _{ID} ≤ −0.2 V	Н	L
Irrelevant	L	Z
Open	Н	?

H = high level, L = low level, Z = high impedance (off), ? = indeterminate

D OR N PACKAGE (TOP VIEW)

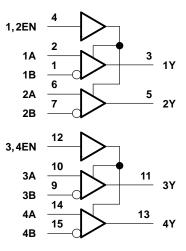


logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)

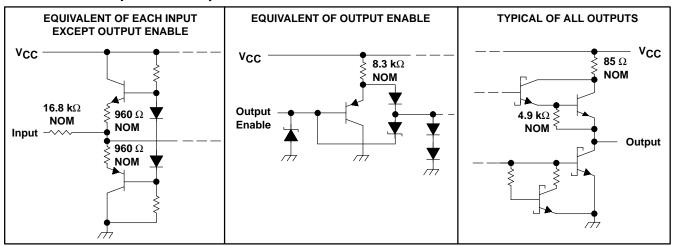


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schematics of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)	8 V
Input voltage, V _I (A or B inputs)	
Differential input voltage, V _{ID} (see Note 2)	±25 V
Enable input voltage	8 V
Low-level output current, I _{OL}	50 mA
Continuous total power dissipation	. See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{stq}	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential-input voltage, are with respect to network ground terminal.
 - 2. Differential-input voltage is measured at the noninverting input with respect to the corresponding inverting input.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING
D	950 mW	7.6 mW/°C	608 mW
N	1150 mW	9.2 mW/°C	736 mW

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.75	5	5.25	V
Common-mode input voltage, V _{IC}			±7	V
Differential input voltage, V _{ID}			±6	V
High-level enable input voltage, VIH	2			V
Low-level enable input voltage, V _{IL}			0.8	V
Operating free-air temperature, T _A	0		70	°C



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electrical characteristics over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature (unless otherwise noted)

	PARAMETER TEST CONDITIONS		MIN	MAX	UNIT	
V _{IT+}	Differential input high-threshold voltage	$V_0 = 2.7 \text{ V}, \qquad I_0 = -0.4 \text{ mA}$			0.2	V
VIT-	Differential input low-threshold voltage	$V_O = 0.5 \text{ V}, \qquad I_O = -8 \text{ mA}$		-0.2†		V
٧ _{IK}	Enable-input clamp voltage	$I_{I} = -10 \text{ mA}$			-1.5	V
VOH	High-level output voltage	$V_{ID} = 0.4 \text{ V},$ $I_{O} = -0.4 \text{ mA},$ See Note 3 and Figure 1		2.7		٧
VOL	Low-level output voltage	$V_{ID} = -0.4 \text{ V}, \qquad I_{O} = 8 \text{ mA},$ See Note 3 and Figure 1			0.5	٧
	I _{OZ} High-impedance-state output current	$V_{IL} = 0.8 \text{ V}, \qquad V_{ID} = -3 \text{ V},$	V _O = 2.7 V		40	μА
102		$V_{IL} = 0.8 \text{ V}, \qquad V_{ID} = 3 \text{ V},$	$V_0 = 0.5 \text{ V}$		-40	
		bias current $V_{CC} = 0 \text{ V or } 5.25 \text{ V,}$ Other inputs at 0 V	$V_{ } = -10 \text{ V}$	-	-3.25	mA
lв	Differential-input bias current		$V_I = -3 V$		-1.5	
l лВ	Differential-input bias current		V _I = 3 V		1.5	
			V _I = 10 V		3.25	
1	High lovel enable input current	V _I = 5.25 V			100	
ΊΗ	High-level enable input current	V _I = 2.7 V			20	μΑ
IլL	Low-level enable input current	$V_{I} = -0.5 V$			-100	μΑ
los	Short-circuit output current	$V_{ID} = 3 V$, $V_{O} = 0$,	See Note 4	-15	-100	mA
ICC	Supply current	V _{IL} = 0			85	mA

[†] The algebraic convention, in which the least positive (most negative) limit is designated as minimum, is used in this data sheet for threshold voltages only.

NOTES: 3. Refer to ANSI Standards EIA/TIA-422-B and EIA/TIA-423-B for exact conditions.

4. Only one output should be shorted at a time.

switching characteristics, V_{CC} = 5 V, C_L = 15 pF, T_A = 25°C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
tPHL	Propagation delay time, high- to low-level output	See Figure 2		28	35	ns
tPLH	Propagation delay time, low- to high-level output			27	30	ns
tPZH	Output enable time to high level	See Figure 3		13	30	ns
tPZL	Output enable time to low level			20	30	ns
tPHZ	Output disable time from high level			26	35	ns
tPLZ	Output disable time from low level			27	35	ns

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PARAMETER MEASUREMENT INFORMATION

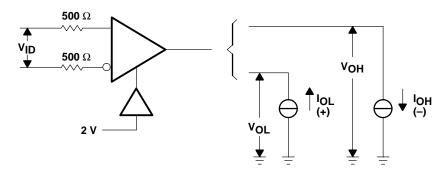


Figure 1. V_{OH}, V_{OL}

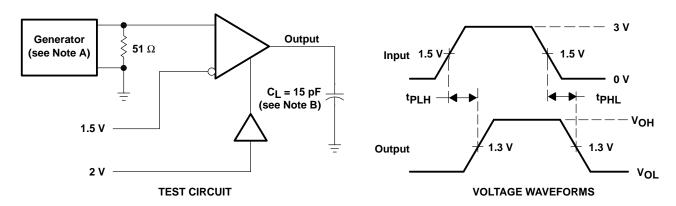


Figure 2. Test Circuit and Voltage Waveforms

NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle = 50%, $t_f \leq$ 6 ns. $t_f \leq$ 6 ns.

B. C_L includes probe and stray capacitance.

PARAMETER MEASUREMENT INFORMATION

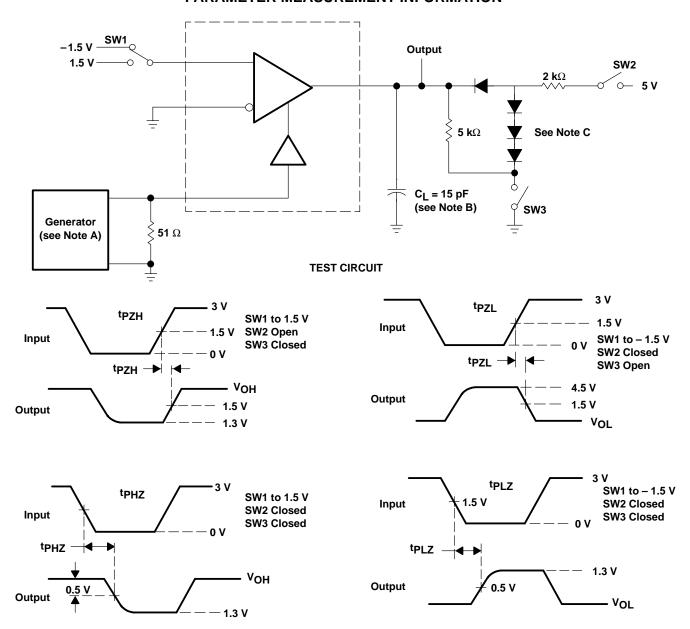


Figure 3. Test Circuit and Voltage Waveforms

NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle = 50%, $t_f \leq$ 6 ns. $t_f \leq$ 6 ns.

- B. C_L includes probe and stray capacitance.
- C. All diodes are 1N916 or equivalent.

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